



(NPN)

FEATURES

Power dissipation

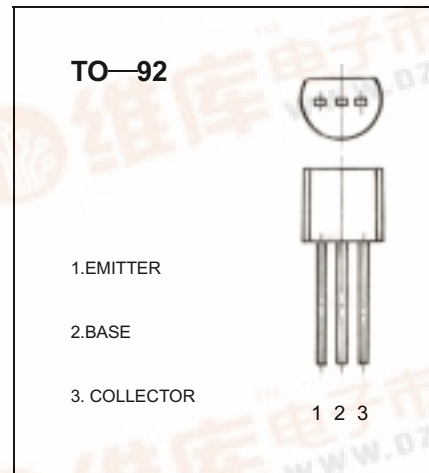
$P_{CM} : 1 \text{ W}$ ($T_{amb}=25^{\circ}\text{C}$)

Collector current

$I_{CM} : 1.5 \text{ A}$

Collector-base voltage

$V_{(BR)CBO} : 40 \text{ V}$



ELECTRICAL CHARACTERISTICS ($T_{amb}=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = 100 \mu\text{A}, I_E = 0$	40			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 0.1 \text{ mA}, I_B = 0$	25			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = 100 \mu\text{A}, I_C = 0$	5			V
Collector cut-off current	I_{CBO}	$V_{CB} = 40 \text{ V}, I_E = 0$			0.1	μA
Collector cut-off current	I_{CEO}	$V_{CB} = 20 \text{ V}, I_E = 0$			0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = 5 \text{ V}, I_C = 0$			0.1	μA
DC current gain(note)	$H_{FE(1)}$	$V_{CE} = 1 \text{ V}, I_C = 100 \text{ mA}$	85		300	
	$H_{FE(2)}$	$V_{CE} = 1 \text{ V}, I_C = 800 \text{ mA}$	40			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 800 \text{ mA}, I_B = 80 \text{ mA}$			0.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = 800 \text{ mA}, I_B = 80 \text{ mA}$			1.2	V
Base-emitter voltage	V_{BE}	$I_E = 1.5 \text{ A}$			1.6	V
Transition frequency	f_T	$V_{CE} = 10 \text{ V}, I_C = 50 \text{ mA}$ $f = 30 \text{ MHz}$	190			MHz

CLASSIFICATION OF $H_{FE(1)}$

Rank	B	C	D
Range	85-160	120-200	160-300

